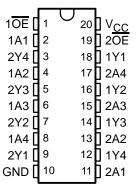
SCLS486A - MAY 2003 - REVISED JUNE 2003

- Controlled Baseline
 - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree[†]
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 1500 V Per MIL-STD-833, Method 3015; Exceeds 150 V Using Machine Model (C = 200 pF, R = 0)

DW OR PW PACKAGE (TOP VIEW)



description/ordering information

This octal buffer/driver is designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The SN74AHC244 is organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

TA	PACK	(AGE‡	ORDERABLE PART NUMBER	TOP-SIDE MARKING
55°C to 125°C	SOIC - D	Tape and reel	SN74AHC244MDWREP	AHC244MEP
–55°C to 125°C	TSSOP – PW	Tape and reel	SN74AHC244MPWREP	AHC244EP

[‡] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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EPIC is a trademark of Texas Instruments.

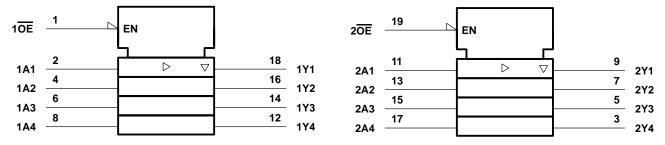


[†] Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

FUNCTION TABLE (each 4-bit buffer/driver)

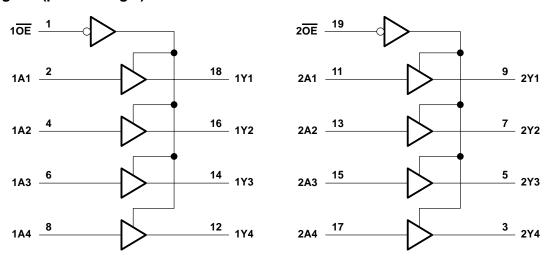
INPU	JTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Output voltage range, V _O (see Note 1)	0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)	
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	58°C/W
PW package	83°C/W
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT	
VCC	Supply voltage		2	5.5	V	
		V _{CC} = 2 V	1.5			
VIH	High-level input voltage	V _{CC} = 3 V	2.1		V	
		V _{CC} = 5.5 V	3.85			
		V _{CC} = 2 V		0.5		
VIL	Low-level input voltage	V _{CC} = 3 V		0.9	V	
		V _{CC} = 5.5 V		1.65		
٧ _I	Input voltage		0	5.5	V	
٧o	Output voltage		0	VCC	V	
		V _{CC} = 2 V		-50	μΑ	
ІОН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA	
	Low-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	$V_{CC} = 5 V \pm 0.5 V$		-8	IIIA	
		V _{CC} = 2 V		50	μΑ	
lOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	~ Λ	
		$V_{CC} = 5 V \pm 0.5 V$		8	mA	
Δt/Δν	Input transition rice or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	ns/V	
Δι/Δν	input transition rise of fail fate	$V_{CC} = 5 V \pm 0.5 V$		20	115/ V	
TA	Operating free-air temperature		-55	125	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-7.

SN74AHC244-EP OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T,	Վ = 25°C	;	MIN	MAY	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	IVIIN	MAX	ONT
		2 V	1.9	2		1.9		
^V OH	I _{OH} = -50 μA	3 V	2.9	3		2.9		
		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1	V
VOL		4.5 V			0.1		0.1	
	I _{OL} = 4 mA	3 V			0.36		0.5	
	I _{OL} = 8 mA	4.5 V			0.36		0.5	
lį	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μΑ
loz	$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.25		±2.5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		2	10			pF
Co	$V_O = V_{CC}$ or GND	5 V		3.5				pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	Τ _Α	_ = 25°C	;	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIV	IVIAA	UNIT
^t PLH	А	Y	C _L = 15 pF		5.8	8.4	1	10	nc
tPHL	A	•	OL = 15 pr		5.8	8.4	1	10	ns
^t PZH	<u>OE</u>	Y	C _I = 15 pF		6.6	10.6	1	12.5	ns
^t PZL	OE	ľ	CL = 15 pr		6.6	10.6	1	12.5	115
^t PHZ	ŌĒ	Y	C _L = 15 pF		5	9.7	1	11	ns
t _{PLZ}	OE		OL = 13 pi		5	9.7	1	11	113
^t PLH	А	Y	C 50 pE		8.3	11.9	1	13.5	ns
^t PHL	A		C _L = 50 pF		8.3	11.9	1	13.5	115
^t PZH	<u>OE</u>	Y	C: - 50 pE		9.1	14.1	1	16	ns
^t PZL	OE	Y C _L = 50 pF			9.1	14.1	1	16	115
t _{PHZ}	ŌĒ	Y	C: = 50 pE		10.3	14	1	16	ne
^t PLZ	OE .	,	Y $C_L = 50 \text{ pF}$		10.3	14	1	16	ns



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	Τ _Δ	= 25°C	;	MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIV	WAX	UNIT
^t PLH	А	Y	C _I = 15 pF		3.9	5.5	1	6.5	ns
t _{PHL}	A	ı	OL = 13 pi		3.9	5.5	1	6.5	115
^t PZH	ŌĒ	Y	C 15 pE		4.7	7.3	1	8.5	no
^t PZL	OE	Y C _L = 15 pF			4.7	7.3	1	8.5	ns
^t PHZ	ŌĒ	Y	C _L = 15 pF		5	7.2	1	8.5	ns
tPLZ	OE	ī	OL = 13 pr		5	7.2	1	8.5	115
^t PLH	А	Y	C _L = 50 pF		5.4	7.5	1	8.5	ns
^t PHL	A	ı			5.4	7.5	1	8.5	115
^t PZH	ŌĒ	Y	C: - 50 pE		6.2	9.3	1	10.5	nc
^t PZL	OE	ı	C _L = 50 pF		6.2	9.3	1	10.5	ns
^t PHZ	ŌĒ	Y	C: - 50 pE		6.7	9.2	1	10.5	200
t _{PLZ}	OE .	ſ	C _L = 50 pF		6.7	9.2	1	10.5	ns

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

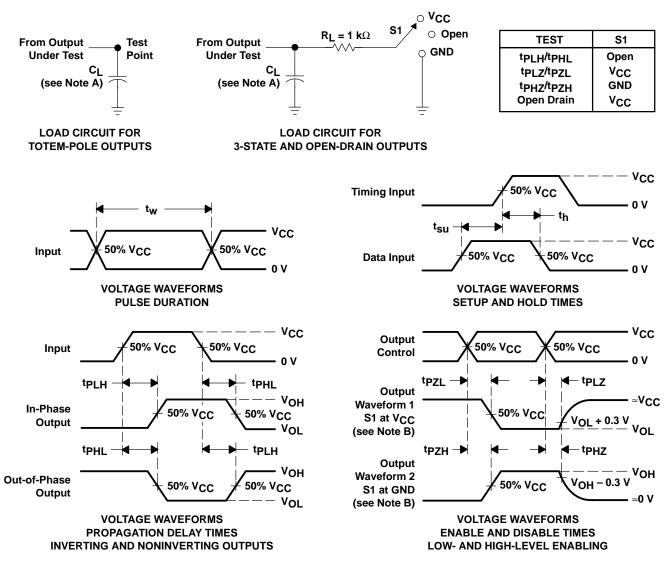
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5		V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.2		V
V _{OH(V)}	Quiet output, minimum dynamic VOH		4.8		V
VIH(D)	High-level dynamic input voltage	3.5			V
V _{IL(D)}	Low-level dynamic input voltage			1.5	V

NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	No load, f = 1 MHz	8.6	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms







11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	_		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
SN74AHC244MDWREP	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC244MEP	Samples
SN74AHC244MPWREP	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC244EP	Samples
SN74AHC244MPWREPG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC244EP	Samples
V62/03649-01XE	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC244EP	Samples
V62/03649-01YE	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	AHC244MEP	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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⁽³⁾ MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.





11-Apr-2013

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AHC244-EP:

Catalog: SN74AHC244

Automotive: SN74AHC244-Q1

Military: SN54AHC244

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC244MDWREP	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC244MPWREP	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC244MDWREP	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC244MPWREP	TSSOP	PW	20	2000	367.0	367.0	38.0

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